

SN74LV74A-Q1 車載用デュアル・ポジティブ・エッジ・トリガ D タイプ・フリップ・フロップ

1 特長

- 車載アプリケーション向け認定済み
- 2V~5.5V の V_{CC} で動作
- 最大 t_{pd} 13ns (5V 時)
- 標準 V_{OLP} (出力グランド・バウンス) $< 0.8V$ ($V_{CC} = 3.3V$, $T_A = 25^\circ C$)
- 標準 V_{OHV} (出力 V_{OH} アンダーシュート) $> 2.3V$ ($V_{CC} = 3.3V$, $T_A = 25^\circ C$)
- すべてのポートで混在モード電圧動作をサポート
- I_{off} により部分的パワーダウン・モードでの動作をサポート
- JESD 17 準拠で 250mA 超のラッチアップ性能

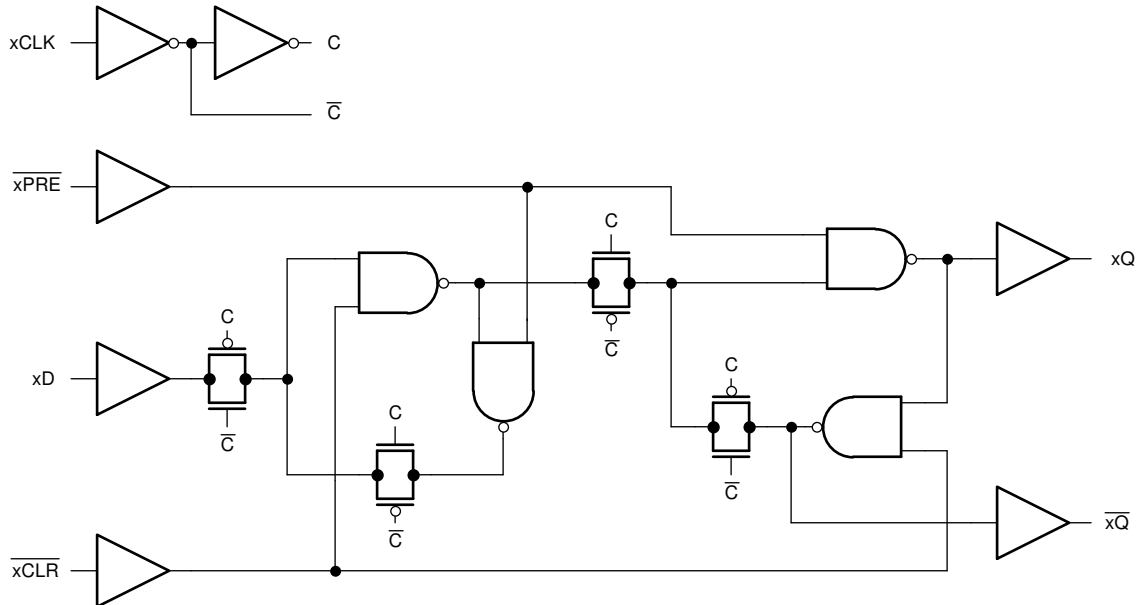
2 概要

このデュアル・ポジティブ・エッジ・トリガ D タイプ・フリップ・フロップは、2V~5.5V の V_{CC} で動作するように設計されています。

パッケージ情報

部品番号	パッケージ ¹	パッケージ・サイズ ²
SN74LV74A-Q1	PW (TSSOP, 14)	5.00mm × 6.4mm
	D (SOIC, 14)	8.65mm × 6mm

- (1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。
- (2) パッケージ・サイズ (長さ×幅) は公称値であり、該当する場合はピンも含まれます。



各フリップ・フロップの論理図 (正論理)



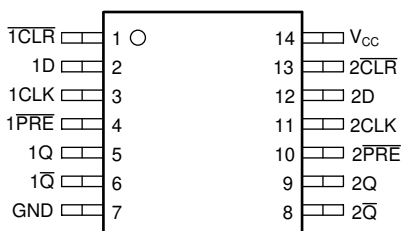
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3 Revision History

Changes from Revision B (April 2008) to Revision C (August 2023)	Page
「パッケージ情報」表、「ピンの機能」表、「ESD 定格」表、「熱に関する情報」表、「デバイスの機能モード」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加.....	1

4 Pin Configuration and Functions



**図 4-1. D and PW Package
14-Pin SOIC and TSSOP
(Top View)**

表 4-1. Pin Functions

PIN NO.	NAME	TYPE ¹	DESCRIPTION
1	1 $\overline{\text{CLR}}$	I	1 clear
2	1D	I	1D input
3	1CLK	I	1 clock
4	1 $\overline{\text{PRE}}$	I	1 preset
5	1Q	O	1Q output
6	1 $\overline{\text{Q}}$	O	1 $\overline{\text{Q}}$ output
7	GND	–	GND
8	2 $\overline{\text{Q}}$	O	2 $\overline{\text{Q}}$ output
9	2Q	O	2Q output
10	2 $\overline{\text{PRE}}$	I	2 preset
11	2CLK	I	2 clock
12	2D	I	2D input
13	2 $\overline{\text{CLR}}$	I	2 clear
14	Vcc	–	Supply voltage input

1. Signal Types: I = Input, O = Output, I/O = Input or Output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		−0.5	7	V
V _I	Input voltage range ⁽²⁾		−0.5	7	V
V _O	Voltage applied to any output in the high-impedance or power-off state ⁽²⁾		−0.5	7	V
V _O	Output voltage range ⁽²⁾ ⁽³⁾		−0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		−20	mA
I _{OK}	Output clamp current	V _O < 0		−50	mA
I _O	Continuous output current	V _O = 0 to V _{CC}	−25	25	mA
	Continuous current through V _{CC} or GND		−50	50	mA
T _{stg}	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value is limited to 5.5-V maximum.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ¹	±2000
		Charged device model (CDM), per AEC Q100-011	±1000

- (1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)¹

		MIN	MAX	UNIT
V _{CC}	Supply voltage	2	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5	V
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7	
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7	
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7	
V _{IL}	Low-level input voltage	V _{CC} = 2 V	0.5	V
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.3	
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.3	
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.3	
V _I	Input voltage	0	5.5	V
V _O	Output voltage	0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 2 V	−50	μA
		V _{CC} = 2.3 V to 2.7 V	−2	mA
		V _{CC} = 3 V to 3.6 V	−6	
		V _{CC} = 4.5 V to 5.5 V	−12	
I _{OL}	Low-level output current	V _{CC} = 2 V	50	μA
		V _{CC} = 2.3 V to 2.7 V	2	mA
		V _{CC} = 3 V to 3.6 V	6	
		V _{CC} = 4.5 V to 5.5 V	12	

over operating free-air temperature range (unless otherwise noted)¹

		MIN	MAX	UNIT
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		200
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		100
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		20
T_A	Operating free-air temperature	-40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

5.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

THERMAL METRIC ⁽¹⁾		D	PW	UNIT
		14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	113	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{OH}	High level output voltage	I _{OH} = −50 μA	2 to 5.5 V	V _{CC} − 0.1		V
		I _{OH} = −2 mA	2.3 V	2		
		I _{OH} = −6 mA	3 V	2.48		
		I _{OH} = −12 mA	4.5 V	3.8		
V _{OL}	Low level output voltage	I _{OL} = 50 μA	2 to 5.5 V		0.1	V
		I _{OL} = 2 mA	2.3 V		0.4	
		I _{OL} = 6 mA	3 V		0.44	
		I _{OL} = 12 mA	4.5 V		0.55	
I _I	Input leakage current	V _I = 5.5 V or GND	0 to 5.5 V		±1	μA
I _{CC}	Supply current	V _I = V _{CC} or GND, I _O = 0	5.5 V		20	μA
I _{off}	Input/Output Power-Off Leakage Current	V _I or V _O = 0 to 5.5 V	0		5	μA
C _i	Input Capacitance	V _I = V _{CC} or GND	3.3 V	2		pF
			5 V	2		

5.6 Timing Requirements, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER		$T_A = 25^\circ C$		MIN	MAX	UNIT
		MIN	MAX			
t_w	Pulse duration	PRE or CLR low		8	9	ns
		CLK		8	9	
t_{su}	Setup time before CLK $\uparrow$	Data		8	9	ns
		PRE or CLR low		7	7	
t_h	Hold time, data after CLK $\uparrow$	0.5		0.5		ns

5.7 Timing Requirements, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER			$T_A = 25^\circ\text{C}$		MIN	MAX	UNIT
			MIN	MAX			
t_w	Pulse duration	PRE or $\overline{\text{CLR}}$ low	6	7			ns
		CLK	6	7			
t_{su}	Setup time before CLK $\uparrow$	Data	6	7			ns
		PRE or $\overline{\text{CLR}}$ low	5	5			
t_h	Hold time, data after CLK $\uparrow$		0.5	0.5			ns

5.8 Timing Requirements, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER			$T_A = 25^\circ\text{C}$		MIN	MAX	UNIT
			MIN	MAX			
t_w	Pulse duration	PRE or $\overline{\text{CLR}}$ low	5	5			ns
		CLK	5	5			
t_{su}	Setup time before CLK $\uparrow$	Data	5	5			ns
		PRE or $\overline{\text{CLR}}$ low	3	3			
t_h	Hold time, data after CLK $\uparrow$		0.5	0.5			ns

5.9 Switching Characteristics, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			MIN	MAX	UNIT
				MIN	TYP	MAX			
f_{max}			$C_L = 50\text{ pF}$	30	70		25		MHz
t_{pd}	PRE or $\overline{\text{CLR}}$	Q or $\overline{Q}$	$C_L = 50\text{ pF}$		13	17.4	1	20	ns
	CLK				14.2	20	1	23	

5.10 Switching Characteristics, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			MIN	MAX	UNIT
				MIN	TYP	MAX			
f_{max}			$C_L = 50\text{ pF}$	50	90		45		MHz
t_{pd}	PRE or $\overline{\text{CLR}}$	Q or $\overline{Q}$	$C_L = 50\text{ pF}$		9.2	15.8	1	18	ns
	CLK				10.2	15.4	1	18	

5.11 Switching Characteristics, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			MIN	MAX	UNIT
				MIN	TYP	MAX			
f_{max}			$C_L = 50\text{ pF}$	90	140		75		MHz
t_{pd}	PRE or $\overline{\text{CLR}}$	Q or $\overline{Q}$	$C_L = 50\text{ pF}$		6.6	9.7	1	12	ns
	CLK				7.2	9.3	1	13	

5.12 Noise Characteristics

$V_{CC} = 3.3\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ ⁽¹⁾

PARAMETER		MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.1	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		0	–0.8	
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		3.2		
$V_{IH(D)}$	High-level dynamic input voltage	2.31			
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	

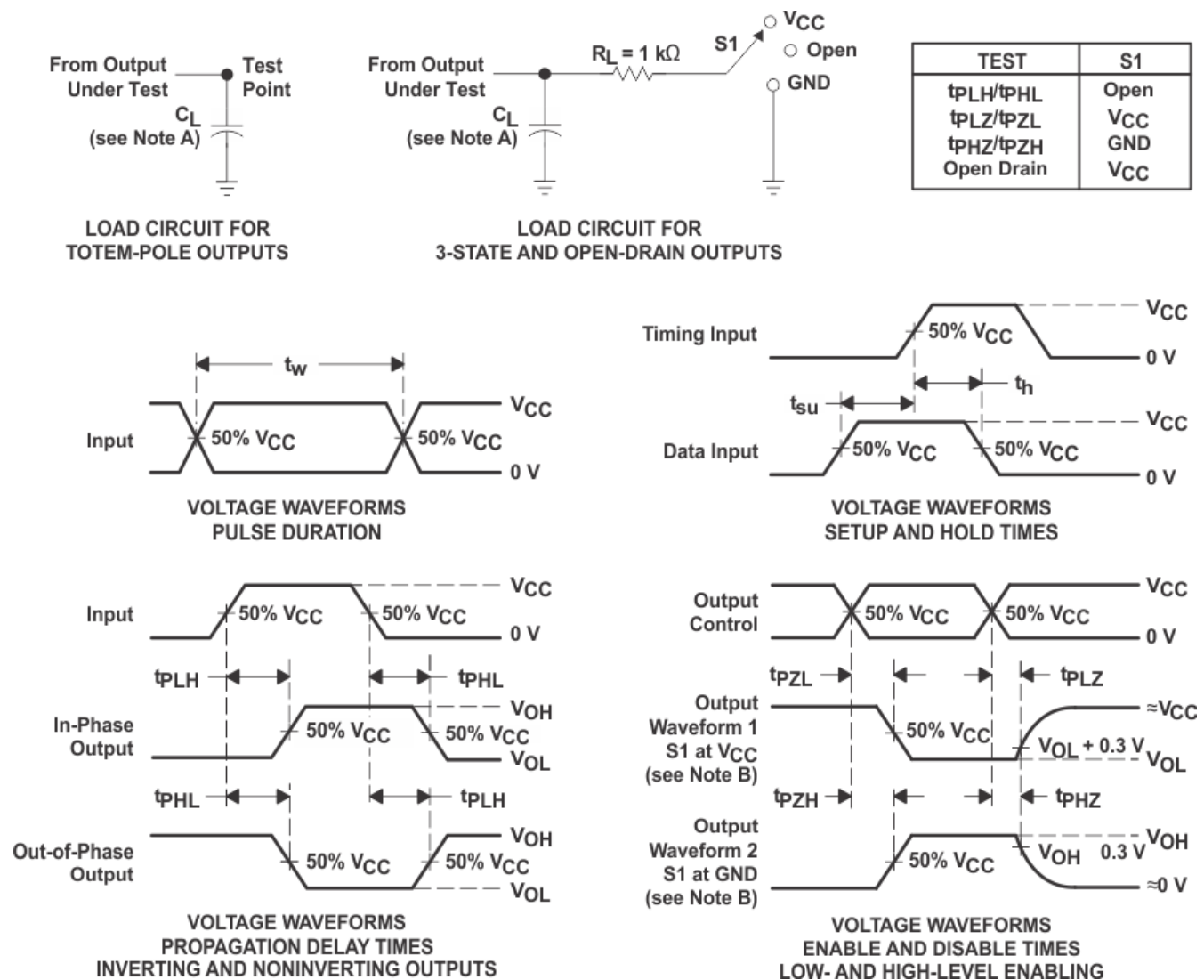
(1) Characteristics are for surface-mount packages only.

5.13 Operating Characteristics

$T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance	$C_L = 50\text{ pF}$, $f = 10\text{ MHz}$	3.3 V	21	pF
			5 V	23	

6 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

FIG 6-1. Load Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

This dual positive-edge-triggered D-type flip-flop is designed for 2-V to 5.5-V V_{CC} operation.

A low level at the preset ($\overline{PRE}$) or clear ($\overline{CLR}$) inputs sets or resets the outputs, regardless of the levels of the other inputs. When $\overline{PRE}$ and $\overline{CLR}$ are inactive (high), data at the data (D) inputs meeting the setup-time requirements is transferred to the outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

7.2 Functional Block Diagram

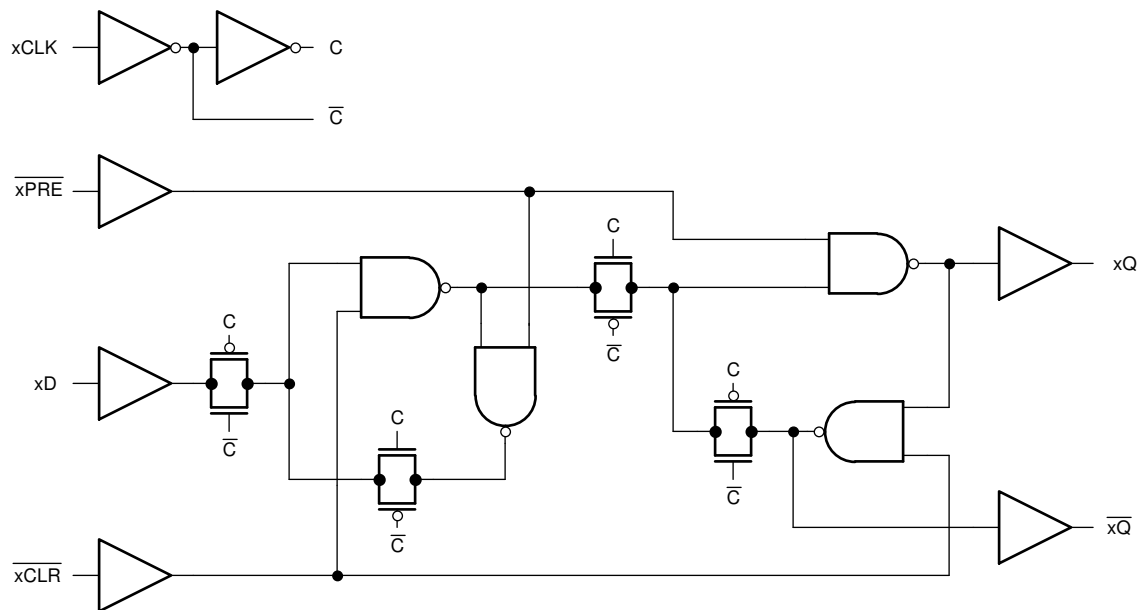


图 7-1. Logic Diagram, Each Flip-flop (Positive Logic)

7.3 Device Functional Modes

表 7-1. Function Table

INPUTS ⁽¹⁾				OUTPUTS ⁽²⁾	
PRE	CLR	CLK	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H ⁽³⁾	H ⁽³⁾
H	H	↑	H	H	L
H	H	↑	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

(1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care

(2) H = Driving High, L = Driving Low, Z = High Impedance State

(3) This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV74A-Q1	Click here	Click here	Click here	Click here	Click here

8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.com のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

8.3 サポート・リソース

TI E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

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8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

8.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV74AQDRG4Q1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A	Samples
SN74LV74AQDRQ1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A	Samples
SN74LV74AQPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV74A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LV74A-Q1 :

- Catalog : [SN74LV74A](#)
- Enhanced Product : [SN74LV74A-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

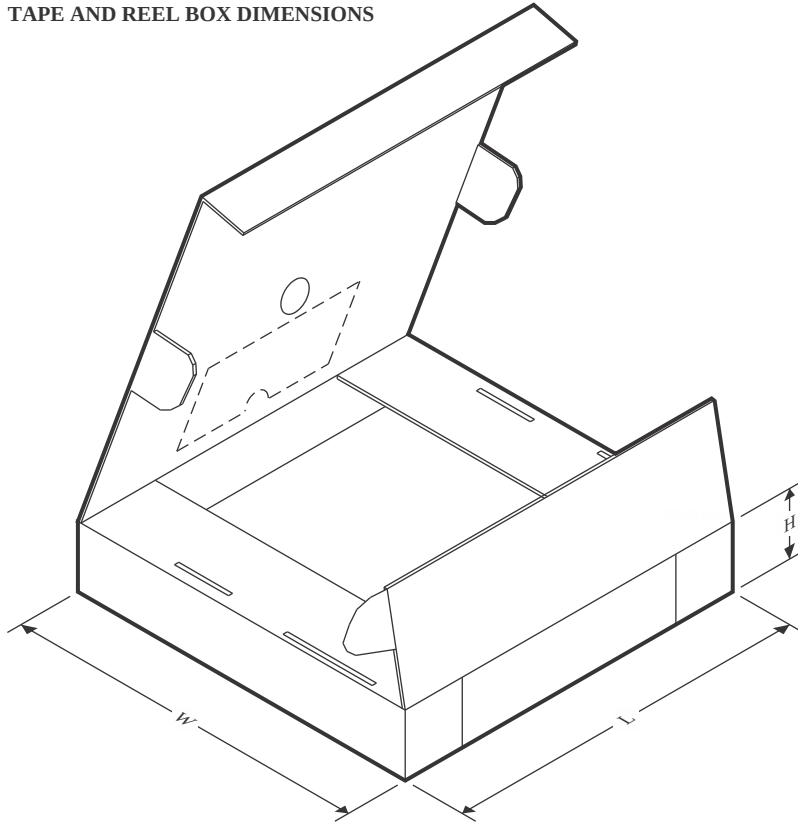
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

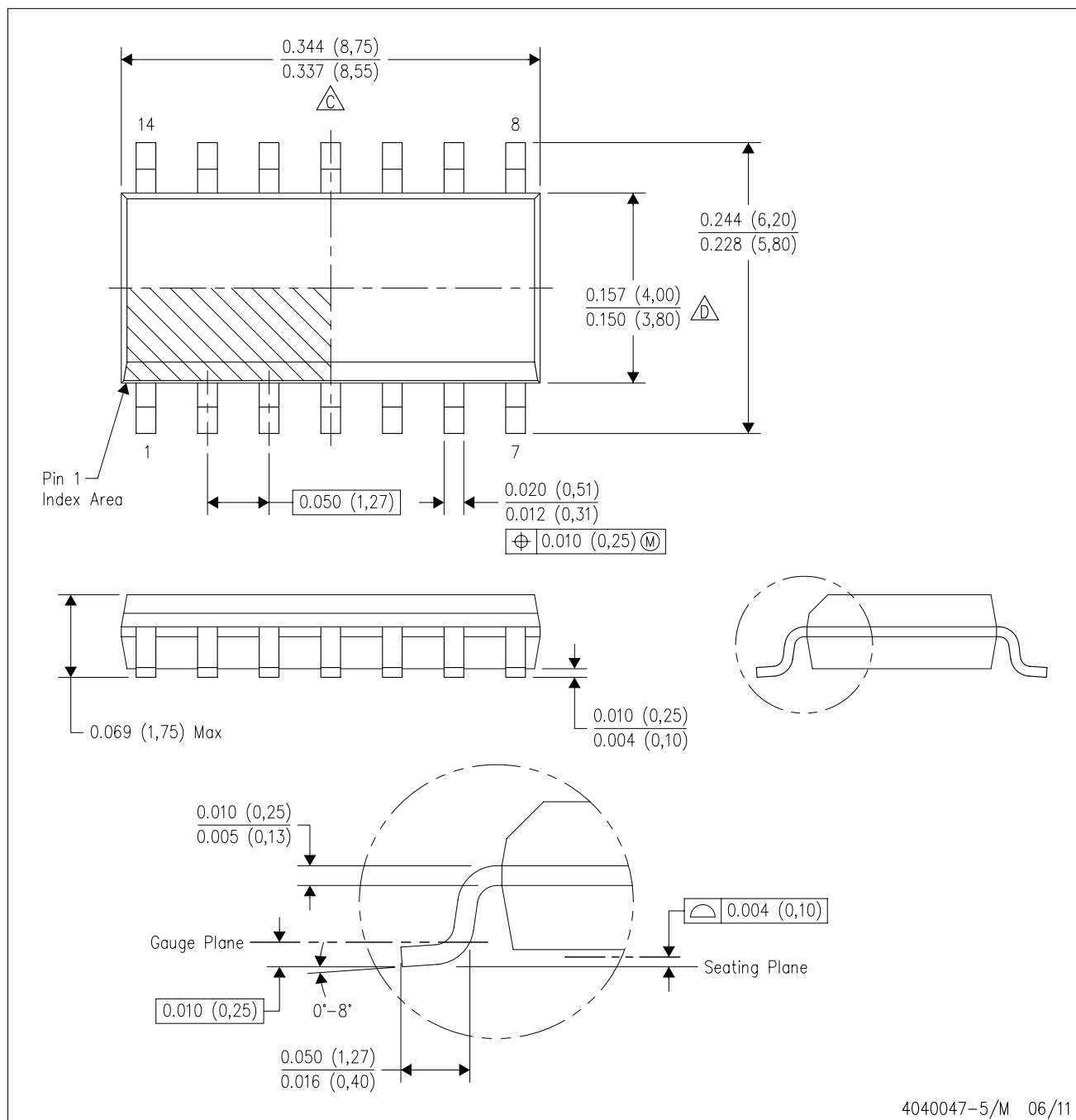


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV74AQPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE

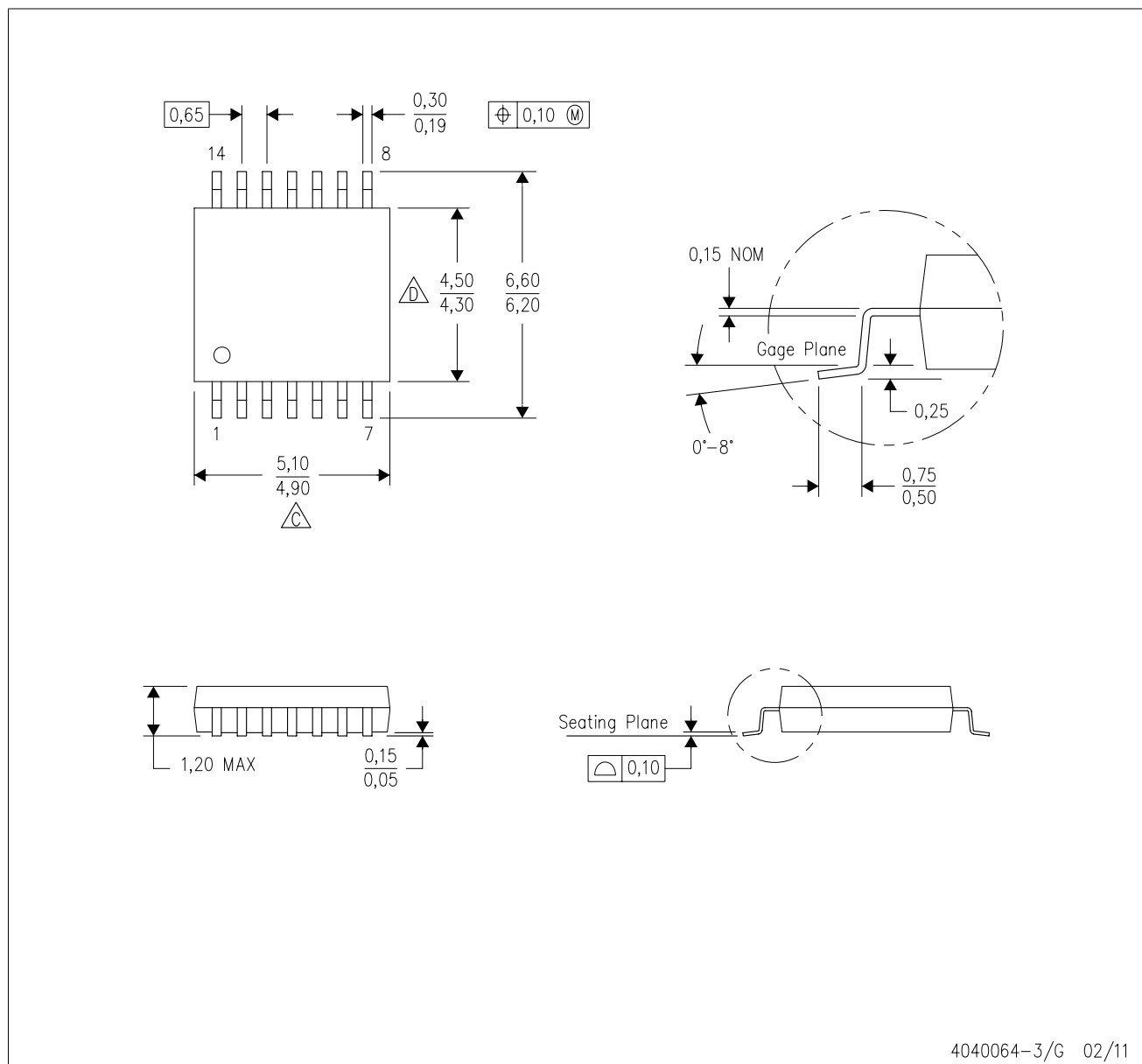


NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS-012 variation AB.

PW (R-PDSO-G14)

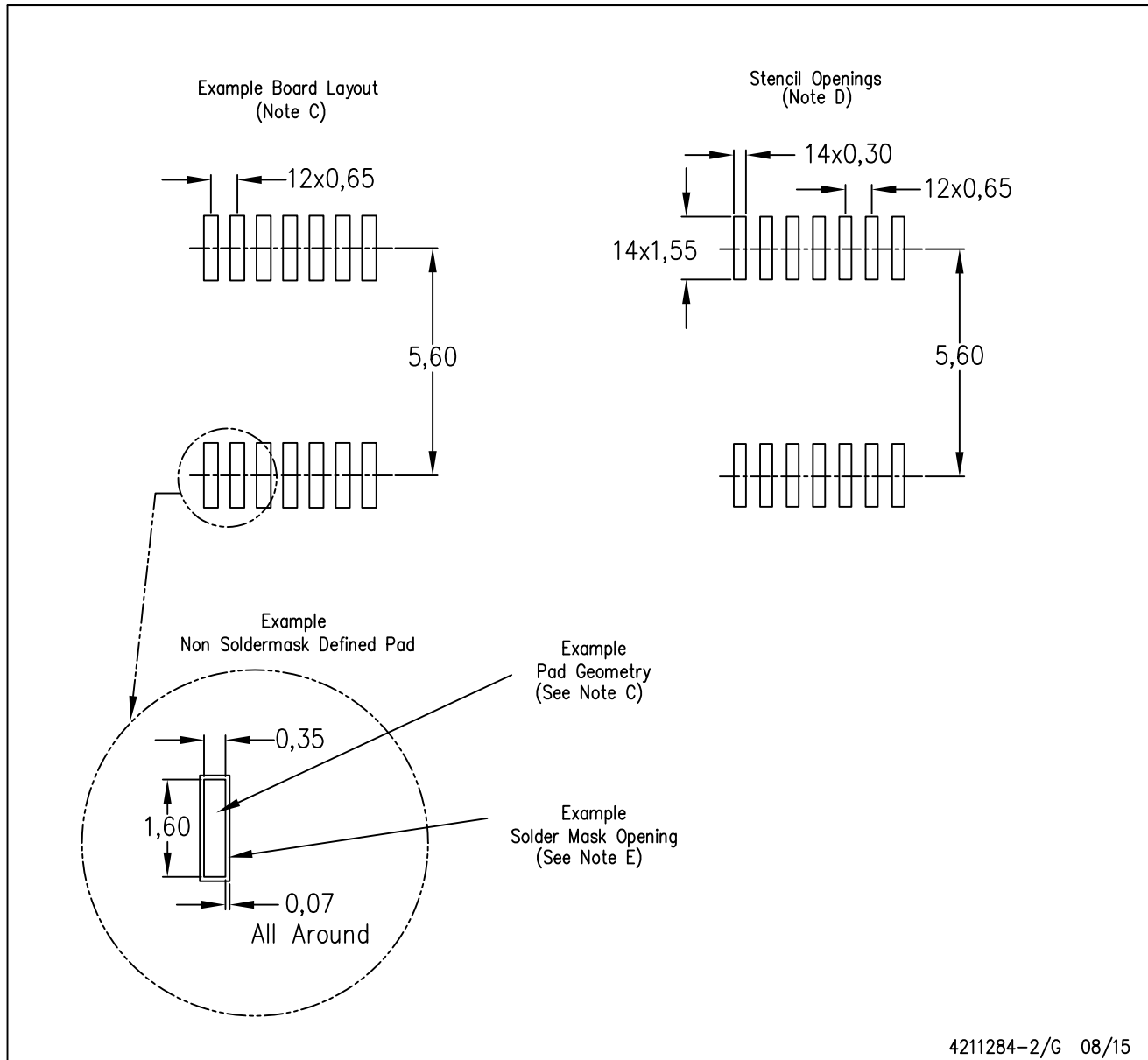
PLASTIC SMALL OUTLINE



4040064-3/G 02/11

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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